
CVD diamond tools — Categorization

Outils diamant CVD — Catégorisation

iTeh STANDARD PREVIEW
(standards.iteh.ai)

[ISO 22180:2019](https://standards.iteh.ai/catalog/standards/sist/f90059e3-8d21-4ea2-afd3-cc54c407bffa/iso-22180-2019)

<https://standards.iteh.ai/catalog/standards/sist/f90059e3-8d21-4ea2-afd3-cc54c407bffa/iso-22180-2019>



iTeh STANDARD PREVIEW (standards.iteh.ai)

ISO 22180:2019

<https://standards.iteh.ai/catalog/standards/sist/f90059e3-8d21-4ea2-afd3-cc54c407bffa/iso-22180-2019>



COPYRIGHT PROTECTED DOCUMENT

© ISO 2019

All rights reserved. Unless otherwise specified, or required in the context of its implementation, no part of this publication may be reproduced or utilized otherwise in any form or by any means, electronic or mechanical, including photocopying, or posting on the internet or an intranet, without prior written permission. Permission can be requested from either ISO at the address below or ISO's member body in the country of the requester.

ISO copyright office
CP 401 • Ch. de Blandonnet 8
CH-1214 Vernier, Geneva
Phone: +41 22 749 01 11
Fax: +41 22 749 09 47
Email: copyright@iso.org
Website: www.iso.org

Published in Switzerland

Contents

	Page
Foreword	iv
1 Scope	1
2 Normative references	1
3 Terms and definitions	1
4 Classification of CVD diamond tools	2
4.1 CVD diamond-coated tools	2
4.2 CVD diamond thick film tools	3
4.3 Classification of CVD diamond tools	4
Annex A (informative) Manufacturing processes — Synthesis of CVD diamond	6
Annex B (informative) CVD diamond coating modifications	7
Annex C (informative) Structure and characteristics of MCD and PCD tools	9
Annex D (informative) Manufacture of CVD diamond-coated tools	12
Bibliography	16

iTeh STANDARD PREVIEW (standards.iteh.ai)

[ISO 22180:2019](https://standards.iteh.ai/catalog/standards/sist/f90059e3-8d21-4ea2-afd3-cc54c407bffa/iso-22180-2019)

<https://standards.iteh.ai/catalog/standards/sist/f90059e3-8d21-4ea2-afd3-cc54c407bffa/iso-22180-2019>

Foreword

ISO (the International Organization for Standardization) is a worldwide federation of national standards bodies (ISO member bodies). The work of preparing International Standards is normally carried out through ISO technical committees. Each member body interested in a subject for which a technical committee has been established has the right to be represented on that committee. International organizations, governmental and non-governmental, in liaison with ISO, also take part in the work. ISO collaborates closely with the International Electrotechnical Commission (IEC) on all matters of electrotechnical standardization.

The procedures used to develop this document and those intended for its further maintenance are described in the ISO/IEC Directives, Part 1. In particular, the different approval criteria needed for the different types of ISO documents should be noted. This document was drafted in accordance with the editorial rules of the ISO/IEC Directives, Part 2 (see www.iso.org/directives).

Attention is drawn to the possibility that some of the elements of this document may be the subject of patent rights. ISO shall not be held responsible for identifying any or all such patent rights. Details of any patent rights identified during the development of the document will be in the Introduction and/or on the ISO list of patent declarations received (see www.iso.org/patents).

Any trade name used in this document is information given for the convenience of users and does not constitute an endorsement.

For an explanation of the voluntary nature of standards, the meaning of ISO specific terms and expressions related to conformity assessment, as well as information about ISO's adherence to the World Trade Organization (WTO) principles in the Technical Barriers to Trade (TBT) see www.iso.org/iso/foreword.html.

This document was prepared by Technical Committee ISO/TC 29, *Small tools*, Subcommittee SC 9, *Tools with defined cutting edges, holding tools, cutting items, adaptive items and interfaces*.

Any feedback or questions on this document should be directed to the user's national standards body. A complete listing of these bodies can be found at www.iso.org/members.html.

CVD diamond tools — Categorization

1 Scope

This document deals with diamond tools whose cutting edges are made of CVD diamond, either as a solid single piece or as a coating. The tool specifications are differentiated into CVD diamond-coated tools (CVD diamond thin-film coatings) and tools with a CVD diamond cutting insert.

According to ISO 513, CVD diamond tools can be classified under “hard coatings of hard metal and ceramic” and “binder-free polycrystalline diamond”. In order to differentiate the CVD diamond tools from tools with monocrystalline synthetic or natural diamond (MCD or monocrystalline diamond) or with sintered diamond with a binder phase (PCD or polycrystalline diamond), the structure and characteristics of MCD and PCD tools with binder phase are also briefly described.

2 Normative references

There are no normative references in this document.

3 Terms and definitions

For the purposes of this document, the following terms and definitions apply.

ISO and IEC maintain terminological databases for use in standardization at the following addresses:

- ISO Online browsing platform: available at <https://www.iso.org/obp>
- IEC Electropedia: available at <http://www.electropedia.org/>

3.1

active brazing

process of joining diamond to a metallic substrate by means of a brazing alloy

Note 1 to entry: The brazing alloy contains so-called active elements (titanium, for example) which form unsaturated carbides with the carbon atoms of the diamond and in this way bond the diamond to the braze material. Brazing of this kind is carried out in a vacuum or in shielding gas atmosphere.

3.2

chemical vapour deposition

CVD

process for manufacturing diamond in most cases at low-pressure and deposition temperatures of 600 °C to 1 000 °C

Note 1 to entry: Polycrystalline, binder-free diamond coatings and even monocrystals can be produced.

3.3

high-pressure high-temperature synthesis

HPHT synthesis

method of manufacturing diamond at a pressure of approximately 6 GPa and temperatures, T , between 1 400 °C and 1 800 °C

Note 1 to entry: It is only possible to manufacture monocrystals by HPHT synthesis.

3.4

monocrystalline diamond

MCD

cutting material made of diamond in natural or synthetic modification [from *HPHT synthesis* (3.3)]

3.5
polycrystalline diamond
PCD

diamond-cutting material which is manufactured by a two-stage high-pressure high-temperature sintering process [HPHT synthesis (3.3)]

Note 1 to entry: The diamond crystallites which are produced in different crystallite sizes in the first step (through HPHT synthesis) are sintered into a cobalt matrix in the second step.

3.6
blank

diamond crystallites which are produced in different crystallite sizes in the first step are sintered into a cobalt matrix in the second step

Note 1 to entry: Due to the conditions of synthesis, the blank is a cylindrical disk with a thickness, s_D , of 300 μm to 2 000 μm .

3.7
cutting insert

platelet made of super-hard cutting material which is brazed onto a *tool holder* (3.9) and is used as a cutting part

3.8
cemented carbide

substrate material that consists of a hard metal phase and a binder phase for use as CVD (3.2) diamond coated thin film cutting tools

Note 1 to entry: Monotungsten carbide (WC) as hard metal combined with cobalt (Co) as a binder phase are commonly referred to as WC-Co. Cemented carbides may also consist of three phases: the Monotungsten carbide phase (WC) as the alpha phase, the binder phase (Co, Ni, etc.) as the beta phase and any other individual or combined carbide (TiC, Ta, NbC, etc.) as the gamma-phase.

3.9
tool holder

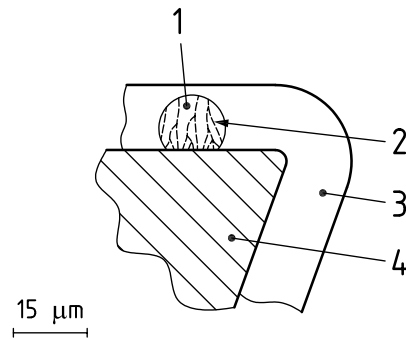
disposable insert or tool shank of which a corner has been ground away and a super-hard *cutting insert* (3.7) brazed on

4 Classification of CVD diamond tools

4.1 CVD diamond-coated tools

Tools made of CVD diamond can be subdivided into two types: CVD diamond coated tools (CVD diamond thin-film tools) in which a coating with thickness, s_D , normally between 1 μm and 40 μm is directly deposited on the tool body, reproducing its shape, and tools with a CVD diamond cutting insert. [Figure 1](#) shows the structure of a CVD diamond coating. An example of a CVD diamond coated tool is shown in [Figure 2](#).

The manufacturing process of the synthesis CVD diamond is represented in [Annex A](#).

**Key**

- 1 diamond grain
- 2 grain boundary
- 3 CVD diamond film
- 4 tool substrate

Figure 1 — Structure of CVD diamond coating**Figure 2 — Example of CVD diamond-coated tool**

CVD diamond coating modifications are displayed in [Annex B](#).

4.2 CVD diamond thick film tools

CVD diamond thick film tools consist of a self-supporting, polycrystalline diamond layer normally between 20 μm and 2 000 μm thick, which is deposited and then cut into geometric sections, as shown in [Figure 3](#). Like PCD, they are then, in a further operation, brazed as cutting inserts onto a tool holder ([Figure 4](#)). The key difference to PCD blanks is that no binder is necessary.



Key

- 1 diamond grains
- 2 grain boundary
- a Polished side of substrate.

Figure 3 — Structure of CVD diamond thick film

Structure and characteristics of MCD and PCD tools are represented in [Annex C](#).



Figure 4 — Example of CVD diamond thick film tool

<https://standards.iteh.ai/catalog/standards/sist/f90059e3-8d21-4ea2-afd3-52e67187/iso-22180-2019>

Since 2005, low-pressure synthesis (CVD process) has also been used for synthesizing monocrystalline CVD diamond (CVD-MCD). This diamond modification has applications in electronics and optics and as well as in machining technology, as shown in [Figure 3](#).

4.3 Classification of CVD diamond tools

[Table 1](#) shows a common example of classification of CVD diamond tools.

NOTE The use of CVD diamond tools is not limited to the examples given in [Table 1](#).

Table 1 — Classification of CVD diamond tools

	Classification of CVD diamond tools	
	CVD diamond-coated tools	CVD diamond thick film tools
Thickness, s_D (μm)	1 to 40	20 to 2 000
Substrate material	WC-Co cemented carbide with cobalt with a maximum mass fraction of 12 %. Amongst ceramic substrates, silicon-based ceramics.	Silicon has established itself as a disposable substrate, and molybdenum as a reusable substrate. In addition, titanium or copper alloys are possible substrate materials.
Carrier material		CVD diamond brazable material
Applicable tools	Drills, tapping tools and shank cutters, microtools, large-diameter tools, indexable inserts for turning and milling operations, sinusoidal.	Disposable inserts for turning, drilling and milling as well as in rotating-shaft tools
Post-treatment (Final processing)	The aim of post-treatment is to give the tool the cutting edge radius required for the cutting or chip-removal application or to create a friction-minimized surface on the normally raw growth side of the diamond film.	As a rule, the high quality requirements can only be satisfied by the mechanical processes of grinding, lapping and polishing as the final processing step. ^a
<p>^a For a long time a characteristic feature of these diamond tools included the production with only two-dimensional cutting-edge geometries. At present they can also be produced with complex or 3-dimensional cutting-edge geometries. An additional geometric modification of diamond cutting parts can be obtained by laser cutting or, in the case of electrically conductive CVD diamond, by electrical discharge machining (EDM) in order to create cutting-edge contours or chip grooves. EDM is made possible by doping with boron during the deposition process.</p>		

Manufacture of CVD diamond-coated tools is listed in [Annex D](#).

ISO 22180:2019

<https://standards.iteh.ai/catalog/standards/sist/f90059e3-8d21-4ea2-afd3-cc54c407bffa/iso-22180-2019>

Annex A (informative)

Manufacturing processes — Synthesis of CVD diamond

CVD techniques allow diamond to be deposited directly onto a series of materials and base geometries. Particularly in the field of machining, where higher performance and improved cost effectiveness in processing new, difficult to machine materials are always demanded, a series of CVD diamond tools has been developed and become commercially available.

Polycrystalline CVD diamond from gas phases is usually manufactured in the low pressure range between 1 hPa and 100 hPa. Either a plasma or a thermal activation of the gas phase is required. Processes which are in industrial use for the deposition of CVD diamond thin film are the hot-filament CVD process and the high-current arc plasma CVD process. For CVD diamond thick film, plasma processes with microwave or direct current (DC) excitation are typically employed.

In hot-filament CVD diamond deposition (HFCVD) the gas phase is activated by filaments of tungsten, tantalum or another refractory metal at filament temperatures of approximately 2 000 °C to 2 800 °C. In plasma-assisted CVD methods (PACVD), microwave plasmas (MW PACVD) or direct-current plasmas (DC PACVD) are usually employed for gas-phase activation. The gas phase to be activated consists for the most part of hydrogen plus an admixture of methane or another hydrocarbon as a source of carbon. This admixture falls within the range of a volume fraction of 0,5 % to 5 %.

Diamond deposition rates depend on the one hand on the activation process the associated CVD process parameters and on the other hand on the materials and geometries to be coated. In the field of CVD diamond tools, deposition rates range from values of around 0,3 µm/h up to some 10 µm/h in the fabrication of CVD diamond thick film by plasma-activated methods.

Electrical conductivity – and thus the electrical discharge machining of CVD diamonds – can be achieved by doping: boron is incorporated during diamond deposition. Doping can have various effects on the behaviour of CVD diamonds used as a cutting material, however.

Annex B (informative)

CVD diamond coating modifications

As a way of improving performance of CVD diamond coatings, according to VDI 2840, CVD coating technology offers the possibility of various diamond coating modifications. The different modifications have differing material properties and can, as such, determine the properties of the cutting tool. Free-standing CVD diamond thick-film has microcrystalline film morphology whereas CVD diamond thin-film systems are classified into microcrystalline, nanocrystalline and multilayer systems.

Microcrystalline films have grains with a columnar structure, having fewer grain boundaries which means that the highest CVD diamond thin-film quality and resistance to abrasive wear can be obtained. Due to the smaller size of the crystallites, nanocrystalline diamond films have a larger number of grain boundaries (see [Figure B.1](#)). [Figure B.2](#) shows the fracture face of a nanocrystalline diamond film. These coatings are characterized by low surface roughness, good frictional properties and high resistance to adhesive wear, and are eminently suitable for post-deposition processing. Resistance to cracking is also improved since the high number of grain boundaries makes it more difficult for cracks to propagate.

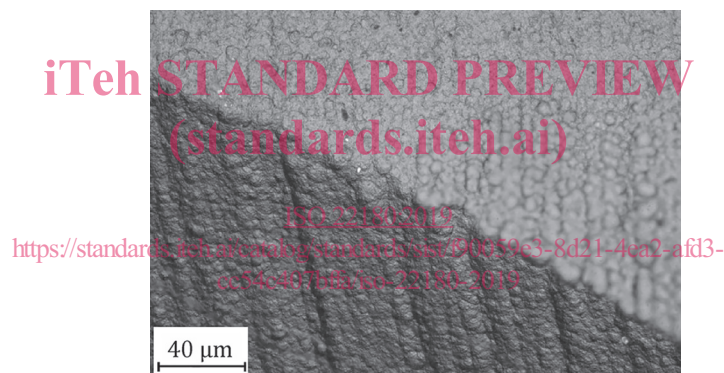


Figure B.1 — Cutting edge with CVD diamond coating (example)

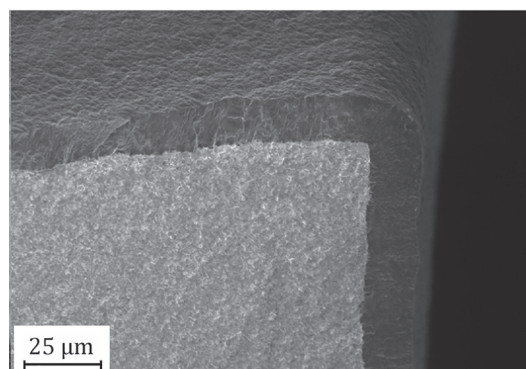


Figure B.2 — Carbide substrate and diamond coating (example)

If the process conditions for depositing microcrystalline and nanocrystalline diamond films are alternated during the coating process a diamond multilayer coating with an almost identical surface quality as is obtained with pure nanocrystalline diamond films results (see [Figure B.3](#)). Adhesion and cracking resistance is further improved since any cracks which do occur will propagate along the individual film layers and thus not reach the interface, the connection of substrate and coating.